



40V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C (Note 6)
-40V	$25m\Omega$ @ V _{GS} = -10V	-8.6A
-40 V	$45m\Omega$ @ V _{GS} = -4.5V	-7.0A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor Control
- Backlighting
- DC-DC Converters
- Printer Equipment

Features

- Low On-Resistance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP4025LK3Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

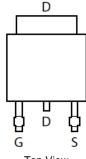
https://www.diodes.com/quality/product-definitions/

Mechanical Data

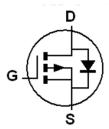
- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.315 grams (Approximate)



Top View



Top View Pin Out



Device symbol

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP4025LK3Q-13	TO252 (DPAK)	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



Oll = Manufacturer's Marking
P4025L = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 20 = 2020)
WW = Week (01 to 53)



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage	Drain-Source Voltage			-40	V
Gate-Source Voltage			V _{GSS}	±20	V
	V _{GS} = -10V	(Note 6)	ID	-8.6	
Continuous Drain Current		$T_A = +70^{\circ}C \text{ (Note 6)}$		-6.9	
		(Note 5)		-6.7	
Pulsed Drain Current	Vgs = -10V	(Note 7)	I _{DM}	-40	Α
Continuous Source Current (Body Diode)		(Note 7)	Is	-8.6	
Pulsed Source Current (Body Diode)		(Note 7)	Ism	-40	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Dawer Dissipation	(Note 5)	D-	1.7	W
Power Dissipation	(Note 6)	P _D	2.78	VV
Thermal Desistance Junction to Ambient	(Note 5)	Devi	74	
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	45	2011
Thermal Resistance, Junction to Case	(Note 6)	R _{θJC}	7.1	°C/W
Thermal Resistance, Junction to Lead (Note 8)		R _{θJL}	1.43	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes:

- 5. For a device surface mounted on minimum recommended FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

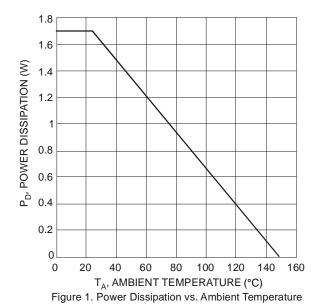
 6. Same as note (5), except the device is surface mounted on 25mm X 25mm X 1.6mm FR4 PCB.

 7. Repetitive rating on 25mm X 25mm FR4 PCB, D=0.02, pulse width 300µs – pulse width by maximum junction temperature.

 8. Thermal resistance from junction to solder-point (at the end of the drain lead).



Thermal Characteristics



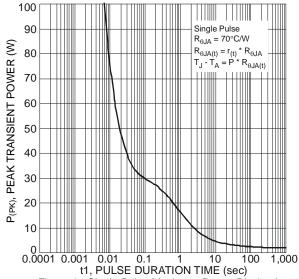
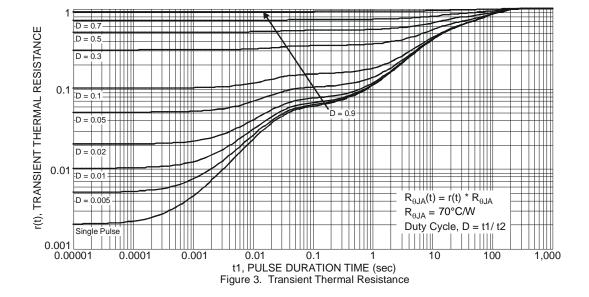


Figure 2. Single Pulse Maximum Power Dissipation





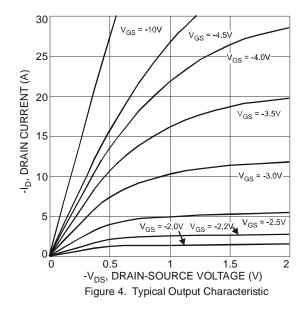
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

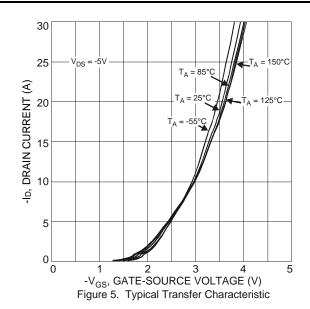
Characteristic	Symbol	Min	Тур	Max	Unit	Test C	ondition	
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	I _D = -250μA, V _{GS} = 0V		
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-1	μΑ	V _{DS} = -40V, V _{GS} = 0V		
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$		
ON CHARACTERISTICS								
Gate Threshold Voltage	Vgs(TH)	-0.8	-1.3	-1.8	V	I _D = -250μA, V _{DS} = V _{GS}		
Static Drain-Source On-Resistance (Note 9)	D		18	25	mΩ	V _G S = -10V, I _D = -3A		
Static Drain-Source On-Resistance (Note 9)	R _{DS(ON)}		30	45	11122	V _G S = -4.5V, I _D = -3A		
Forward Transconductance (Notes 9 & 10)	G fs	_	16.6	_	S	V _{DS} = -5V, I _D =	-3A	
Diode Forward Voltage (Note 9)	VsD	_	-0.7	-1	V	Is = -1A, VGS = 0V		
DYNAMIC CHARACTERISTICS (Note 10)								
Input Capacitance	Ciss	_	1643	_		pF		
Output Capacitance	Coss	_	179	_	pF			
Reverse Transfer Capacitance	Crss	_	128	_		I = IIVII IZ		
Gate Resistance	Rg	_	6.43	_	Ω	V _{DS} = 0V, V _{GS} =	= 0V, f = 1MHz	
Total Gate Charge (Note 11)	Qg	_	14	_		$V_{GS} = -4.5V$		
Total Gate Charge (Note 11)	Qg	_	33.7	_		$V_{GS} = -10V$ $V_{DS} = -20V$ $I_{D} = -3A$	V _{DS} = -20V	
Gate-Source Charge (Note 11)	Qgs	_	5.5	_	nC		$I_D = -3A$	
Gate-Drain Charge (Note 11)	Qgd	_	7.3	_				
Turn-On Delay Time (Note 11)	t _D (ON)	_	6.9	_		·		
Turn-On Rise Time (Note 11)	t _R	_	14.7	_	20	$V_{DD} = -20V, V_{G}$	= -20V, V _{GS} = -10V	
Turn-Off Delay Time (Note 11)	tD(OFF)	_	53.7		ns	I _D = -3A		
Turn-Off Fall Time (Note 11)	tF	_	30.9	_				

Notes:

- 9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s;$ duty cycle $\leq 2\%.$
- 10. For design aid only, not subject to production testing.
 11. Switching characteristics are independent of operating junction temperatures.

Typical Characteristics







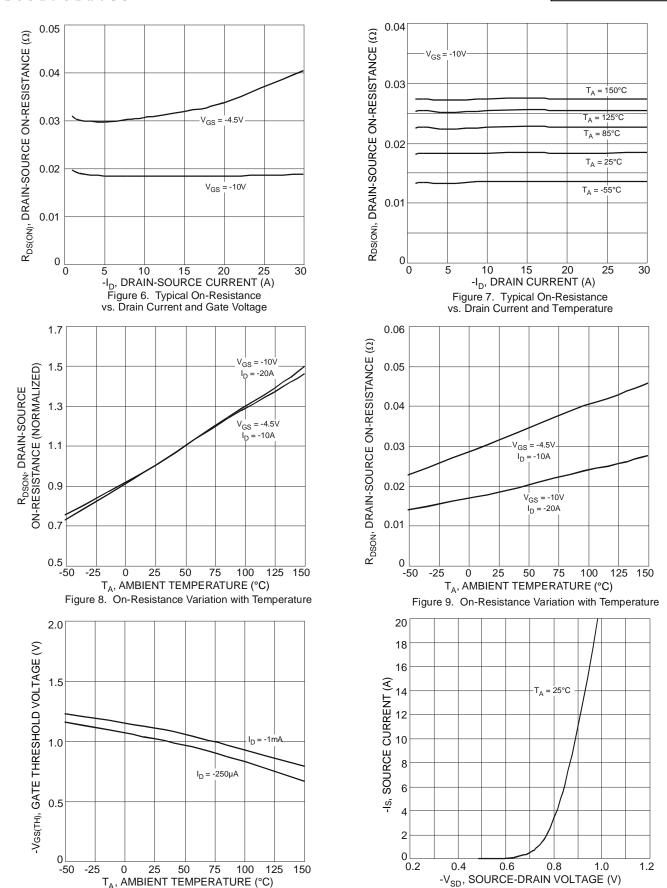
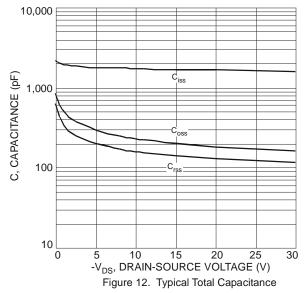
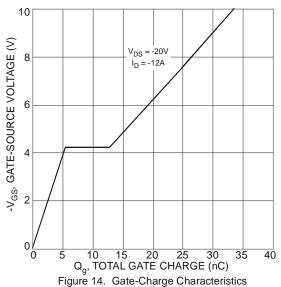


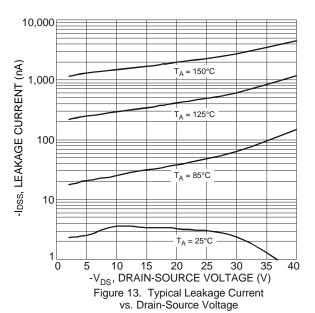
Figure 10. Gate Threshold Variation vs. Ambient Temperature

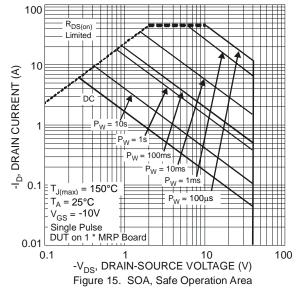
Figure 11. Diode Forward Voltage vs. Current









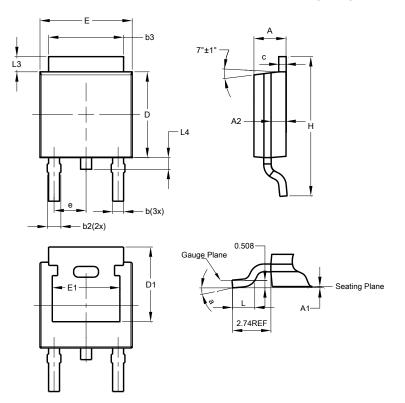




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)

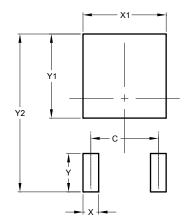


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A 1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
O	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
٦	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Υ	2.600		
Y1	5.700		
Y2	10.700		



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